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January 2016

Single-Channel: 6N137M, HCPL2601M, HCPL2611M Dual-Channel: HCPL2630M, HCPL2631M 8-Pin DIP High-Speed 10 MBit/s Logic Gate Optocouplers

Features

- Very High Speed – 10 MBit/s
- Superior CMR – 10 kV/μs
- Fan-out of 8 Over -40°C to +85°C
- Logic Gate Output
- Strobable Output
- Wired OR-open Collector
- Safety and Regulatory Approvals
 - UL1577, 5,000 VAC_{RMS} for 1 Minute
 - DIN EN/IEC60747-5-5

Applications

- Ground Loop Elimination
- LSTTL to TTL, LSTTL or 5 V CMOS
- Line Receiver, Data Transmission
- Data Multiplexing
- Switching Power Supplies
- Pulse Transformer Replacement
- Computer-peripheral Interface

Description

The 6N137M, HCPL2601M, HCPL2611M single-channel and HCPL2630M, HCPL2631M dual-channel optocouplers consist of a 850 nm AlGaAs LED, optically coupled to a very high speed integrated photo-detector logic gate with a strobable output. This output features an open collector, thereby permitting wired OR outputs. The switching parameters are guaranteed over the temperature range of -40°C to +85°C. A maximum input signal of 5 mA will provide a minimum output sink current of 13 mA (fan out of 8).

An internal noise shield provides superior common mode rejection of typically 10 kV/μs. The HCPL2601M and HCPL2631M has a minimum CMR of 5 kV/μs. The HCPL2611M has a minimum CMR of 10 kV/μs.

Schematics



A 0.1μF bypass capacitor must be connected between pins 8 and 5⁽¹⁾.

Figure 1. Schematics

Package Outlines



Figure 2. Package Options

Truth Table (Positive Logic)

| Input | Enable | Output |
|-------|--------|--------|
| H | H | L |
| L | H | H |
| H | L | H |
| L | L | H |
| H | NC | L |
| L | NC | H |

Single-Channel: 6N137M, HCPL2601M, HCPL2611M
Dual-Channel: HCPL2630M, HCPL2631M — 8-Pin DIP High-Speed 10 MBit/s Logic Gate Optocouplers

Safety and Insulation Ratings

As per DIN EN/IEC 60747-5-5, this optocoupler is suitable for "safe electrical insulation" only within the safety limit data. Compliance with the safety ratings shall be ensured by means of protective circuits.

| Parameter | Characteristics | |
|---|------------------------|-------|
| Installation Classifications per DIN VDE 0110/1.89 Table 1, For Rated Mains Voltage | < 150 V _{RMS} | I-IV |
| | < 300 V _{RMS} | I-IV |
| | < 450 V _{RMS} | I-III |
| | < 600 V _{RMS} | I-III |
| Climatic Classification | 40/100/21 | |
| Pollution Degree (DIN VDE 0110/1.89) | 2 | |
| Comparative Tracking Index | 175 | |

| Symbol | Parameter | Value | Unit |
|-----------------------|--|-------------------|-------------------|
| V _{PR} | Input-to-Output Test Voltage, Method A, V _{IORM} × 1.6 = V _{PR} , Type and Sample Test with t _m = 10 s, Partial Discharge < 5 pC | 1,335 | V _{peak} |
| | Input-to-Output Test Voltage, Method B, V _{IORM} × 1.875 = V _{PR} , 100% Production Test with t _m = 1 s, Partial Discharge < 5 pC | 1,669 | V _{peak} |
| V _{IORM} | Maximum Working Insulation Voltage | 890 | V _{peak} |
| V _{IOTM} | Highest Allowable Over-Voltage | 6,000 | V _{peak} |
| | External Creepage | ≥ 8.0 | mm |
| | External Clearance | ≥ 7.4 | mm |
| | External Clearance (for Option TV, 0.4" Lead Spacing) | ≥ 10.16 | mm |
| DTI | Distance Through Insulation (Insulation Thickness) | ≥ 0.5 | mm |
| T _S | Case Temperature ⁽²⁾ | 150 | °C |
| I _{S,INPUT} | Input Current ⁽²⁾ | 200 | mA |
| P _{S,OUTPUT} | Output Power (Duty Factor ≤ 2.7%) ⁽²⁾ | 300 | mW |
| R _{IO} | Insulation Resistance at T _S , V _{IO} = 500 V ⁽²⁾ | > 10 ⁹ | Ω |

Notes:

- The V_{CC} supply to each optoisolator must be bypassed by a 0.1 μF capacitor or larger. This can be either a ceramic or solid tantalum capacitor with good high frequency characteristic and should be connected as close as possible to the package V_{CC} and GND pins of each device.
- Safety limit value - maximum values allowed in the event of a failure.

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. $T_A = 25^\circ\text{C}$ unless otherwise specified.

| Symbol | Parameter | Value | Unit | |
|-----------------|---|----------------|------------------|------|
| T_{STG} | Storage Temperature | -40 to +125 | $^\circ\text{C}$ | |
| T_{OPR} | Operating Temperature | -40 to +100 | $^\circ\text{C}$ | |
| T_J | Junction Temperature | -40 to +125 | $^\circ\text{C}$ | |
| T_{SOL} | Lead Solder Temperature | 260 for 10 sec | $^\circ\text{C}$ | |
| Symbol | Parameter | Device | Value | Unit |
| EMITTER | | | | |
| I_F (avg) | DC/Average Forward Input Current Per Channel | Single Channel | 50 | mA |
| | | Dual Channel | 30 | |
| V_E | Enable Input Voltage Not to Exceed V_{CC} by more than 500 mV | Single Channel | 5.5 | V |
| V_R | Reverse Input Voltage Per Channel | All | 5.0 | V |
| P_I | Input Power Dissipation Per Channel | Single Channel | 100 | mW |
| | | Dual Channel | 45 | |
| DETECTOR | | | | |
| V_{CC} | Supply Voltage | All | -0.5 to 7.0 | V |
| I_O (avg) | Average Output Current Per Channel | All | 25 | mA |
| I_O (pk) | Peak Output Current Per Channel | All | 50 | mA |
| V_O | Output Voltage Per Channel | All | -0.5 to 7.0 | V |
| P_O | Output Power Dissipation Per Channel | Single Channel | 85 | mW |
| | | Dual Channel | 60 | |

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to absolute maximum ratings.

| Symbol | Parameter | Min. | Max. | Unit |
|----------|-------------------------------|--------------------|----------|------------------|
| V_{CC} | Supply Voltage | 4.5 | 5.5 | V |
| I_{FL} | Input Current, Low Level | 0 | 250 | μA |
| I_{FH} | Input Current, High Level | 6.3 ⁽³⁾ | 20.0 | mA |
| V_{EL} | Enable Voltage, Low Level | 0 | 0.8 | V |
| V_{EH} | Enable Voltage, High Level | 2.0 | V_{CC} | V |
| T_A | Ambient Operating Temperature | -40 | +85 | $^\circ\text{C}$ |
| N | Fan Out (TTL load) | | 8 | |

Note:

- 6.3 mA is a guard banded value which allows for at least 20% CTR degradation. Initial input current threshold value is 5.0 mA or less.

Electrical Characteristics

Individual Component Characteristics ($V_{CC} = 5.5\text{ V}$, $T_A = 0^\circ\text{C}$ to 70°C unless otherwise specified)

| Symbol | Parameter | Device | Test Conditions | Min. | Typ. | Max. | Unit |
|---------------------------|--|----------------|--|------|------|------|----------------------|
| EMITTER | | | | | | | |
| V_F | Input Forward Voltage | All | $I_F = 10\text{ mA}$, $T_A = 25^\circ\text{C}$ | | 1.45 | 1.70 | V |
| | | | $I_F = 10\text{ mA}$ | | | 1.80 | |
| B_{VR} | Input Reverse Breakdown Voltage | All | $I_R = 10\text{ }\mu\text{A}$ | 5.0 | | | V |
| C_{IN} | Input Capacitance | All | $V_F = 0$, $f = 1\text{ MHz}$ | | 60 | | pF |
| $\Delta V_F / \Delta T_A$ | Temperature Coefficient of Forward Voltage | All | $I_F = 10\text{ mA}$ | | -1.4 | | mV/ $^\circ\text{C}$ |
| DETECTOR | | | | | | | |
| I_{CCL} | Logic Low Supply Current | Single Channel | $I_F = 10\text{ mA}$, $V_O = \text{Open}$, $V_E = 0.5\text{ V}$ | | 8 | 13 | mA |
| | | Dual Channel | $I_{F1} = I_{F2} = 10\text{ mA}$, $V_O = \text{Open}$ | | 14 | 21 | |
| I_{CCH} | Logic High Supply Current | Single Channel | $I_F = 0\text{ mA}$, $V_O = \text{Open}$, $V_E = 0.5\text{ V}$ | | 6 | 10 | mA |
| | | Dual Channel | $I_F = 0\text{ mA}$, $V_O = \text{Open}$, | | 10 | 15 | |
| I_{EL} | Low Level Enable Current | Single Channel | $V_E = 0.5\text{ V}$ | | -0.7 | -1.6 | mA |
| I_{EH} | High Level Enable Current | Single Channel | $V_E = 2.0\text{ V}$ | | -0.5 | -1.6 | mA |
| V_{EL} | Low Level Enable Voltage | Single Channel | $I_F = 10\text{ mA}^{(4)}$ | | | 0.8 | V |
| V_{EH} | High Level Enable Voltage | Single Channel | $I_F = 10\text{ mA}$ | 2.0 | | | V |

Note:

4. Enable Input – No pull up resistor required as the device has an internal pull up resistor.

Transfer Characteristics ($V_{CC} = 5.5\text{ V}$, $T_A = -40^\circ\text{C}$ to $+85^\circ\text{C}$ unless otherwise specified)

| Symbol | Parameter | Device | Test Conditions | Min. | Typ. | Max. | Unit |
|----------|---------------------------|--------|---|------|------|------|---------------|
| I_{FT} | Input Threshold Current | All | $V_O = 0.6\text{ V}$, $V_E = 2.0\text{ V}$, $I_{OL} = 13\text{ mA}$ | | 3 | 5 | mA |
| I_{OH} | HIGH Level Output Current | All | $V_O = 5.5\text{ V}$, $I_F = 250\text{ }\mu\text{A}$, $V_E = 2.0\text{ V}$ | | | 100 | μA |
| V_{OL} | LOW Level Output Voltage | All | $I_F = 5\text{ mA}$, $V_E = 2.0\text{ V}$, $I_{OL} = 13\text{ mA}$ | | 0.4 | 0.6 | V |

Electrical Characteristics (Continued)

Switching Characteristics ($V_{CC} = 5\text{ V}$, $I_F = 7.5\text{ mA}$, $T_A = -40^\circ\text{C}$ to $+85^\circ\text{C}$ unless otherwise specified)

| Symbol | Parameter | Device | Test Conditions | Min. | Typ. | Max. | Unit |
|-----------------------|--|----------------------|---|--------|--------|------|------------------|
| t_{PHL} | Propagation Delay Time to Logic LOW | All | $R_L = 350\ \Omega$, $C_L = 15\text{ pF}$, $T_A = 25^\circ\text{C}^{(5)}$ (Fig. 14) | 25 | 40 | 75 | ns |
| | | | $R_L = 350\ \Omega$, $C_L = 15\text{ pF}^{(6)}$ (Fig. 14) | | | 100 | |
| t_{PLH} | Propagation Delay Time to Logic HIGH | All | $R_L = 350\ \Omega$, $C_L = 15\text{ pF}$, $T_A = 25^\circ\text{C}^{(6)}$ (Fig. 14) | 20 | 40 | 75 | ns |
| | | | $R_L = 350\ \Omega$, $C_L = 15\text{ pF}^{(6)}$ (Fig. 14) | | | 100 | |
| $ t_{PHL} - t_{PLH} $ | Pulse Width Distortion | All | $R_L = 350\ \Omega$, $C_L = 15\text{ pF}$ (Fig. 14) | | 1 | 35 | ns |
| t_R | Output Rise Time (10% to 90%) | All | $R_L = 350\ \Omega$, $C_L = 15\text{ pF}^{(7)}$ (Fig. 14) | | 30 | | ns |
| t_F | Output Fall Time (90% to 10%) | All | $R_L = 350\ \Omega$, $C_L = 15\text{ pF}^{(8)}$ (Fig. 14) | | 10 | | ns |
| t_{EHL} | Enable Propagation Delay Time to Output LOW Level | Single Channel | $V_{EH} = 3.5\text{ V}$, $R_L = 350\ \Omega$, $C_L = 15\text{ pF}^{(9)}$ (Fig. 15) | | 15 | | ns |
| t_{ELH} | Enable Propagation Delay Time to Output HIGH Level | Single Channel | $V_{EH} = 3.5\text{ V}$, $R_L = 350\ \Omega$, $C_L = 15\text{ pF}^{(10)}$ (Fig. 15) | | 15 | | ns |
| $ CM_H $ | Common Mode Transient Immunity at Logic High | 6N137M, HCPL2630M | $I_F = 0\text{ mA}$, $V_{CM} = 50\text{ V}_{PEAK}$, $R_L = 350\ \Omega$, $T_A = 25^\circ\text{C}^{(11)}$ (Fig. 16) | | 10,000 | | V/ μs |
| | | HCPL2601M, HCPL2631M | | 5000 | 10,000 | | |
| | | HCPL2611M | | 10,000 | 15,000 | | |
| $ CM_L $ | Common Mode Transient Immunity at Logic Low | 6N137M, HCPL2630M | $V_{CM} = 50\text{ V}_{PEAK}$, $R_L = 350\ \Omega$, $T_A = 25^\circ\text{C}^{(11)}$ (Fig. 16) | | 10,000 | | V/ μs |
| | | HCPL2601M, HCPL2631M | | 5000 | 10,000 | | |
| | | HCPL2611M | | 10,000 | 15,000 | | |

Notes:

- t_{PHL} – Propagation delay is measured from the 3.75 mA level on the LOW to HIGH transition of the input current pulse to the 1.5 V level on the HIGH to LOW transition of the output voltage pulse.
- t_{PLH} – Propagation delay is measured from the 3.75 mA level on the HIGH to LOW transition of the input current pulse to the 1.5 V level on the LOW to HIGH transition of the output voltage pulse.
- t_R – Rise time is measured from the 90% to the 10% levels on the LOW to HIGH transition of the output pulse.
- t_F – Fall time is measured from the 10% to the 90% levels on the HIGH to LOW transition of the output pulse.
- t_{EHL} – Enable input propagation delay is measured from the 1.5 V level on the LOW to HIGH transition of the input voltage pulse to the 1.5 V level on the HIGH to LOW transition of the output voltage pulse.
- t_{ELH} – Enable input propagation delay is measured from the 1.5 V level on the HIGH to LOW transition of the input voltage pulse to the 1.5 V level on the LOW to HIGH transition of the output voltage pulse.
- Common mode transient immunity in logic high level is the maximum tolerable (positive) dV_{cm}/dt on the leading edge of the common mode pulse signal, V_{CM} , to assure that the output will remain in a logic high state (i.e., $V_O > 2.0\text{ V}$). Common mode transient immunity in logic low level is the maximum tolerable (negative) dV_{cm}/dt on the trailing edge of the common mode pulse signal, V_{CM} , to assure that the output will remain in a logic low state (i.e., $V_O < 0.8\text{ V}$).

Electrical Characteristics (Continued)

Isolation Characteristics ($T_A = 25^\circ\text{C}$ unless otherwise specified.)

| Symbol | Parameter | Device | Test Conditions | Min. | Typ. | Max. | Unit |
|------------------|---|--------|---|-------|-----------|------|---------------------------|
| V_{ISO} | Withstand Insulation Test Voltage | All | Relative Humidity $\leq 50\%$, $I_{\text{I-O}} \leq 10 \mu\text{A}$, $t = 1 \text{ min}$, $f = 50 \text{ Hz}^{(12)(13)}$ | 5,000 | | | VAC_{RMS} |
| $R_{\text{I-O}}$ | Resistance (Input to Output) | All | $V_{\text{I-O}} = 500 \text{ V}_{\text{DC}}^{(12)}$ | | 10^{11} | | Ω |
| $C_{\text{I-O}}$ | Capacitance (Input to Output) | All | $f = 1 \text{ MHz}$, $V_{\text{I-O}} = 0 \text{ V}_{\text{DC}}^{(12)}$ | | 1 | | pF |
| $I_{\text{I-O}}$ | Input-Output Insulation Leakage Current | All | Relative Humidity $\leq 45\%$, $V_{\text{I-I}} = 3000 \text{ V}_{\text{DC}}$, $t = 5 \text{ sec}^{(12)}$ | | | 1.0 | μA |

Notes:

12. Device is considered a two terminal device: pins 1, 2, 3 and 4 are shorted together and pins 5, 6, 7 and 8 are shorted together.
13. 5000 VAC_{RMS} for 1 minute duration is equivalent to 6000 VAC_{RMS} for 1 second duration.

Typical Performance Curves

For Single-Channel Devices: 6N137M, HCPL2601M, and HCPL2611M



Figure 3. Low Level Output Voltage vs. Ambient Temperature



Figure 4. Input Diode Forward Voltage vs. Forward Current



Figure 5. Switching Time vs. Forward Current



Figure 6. Low Level Output vs. Ambient Temperature



Figure 7. Input Threshold Current vs. Ambient Temperature



Figure 8. Output Voltage vs. Input Forward Current

Typical Performance Curves (Continued)

For Single-Channel Devices: 6N137M, HCPL2601M, HCPL2611M



Figure 9. Pulse Width Distortion vs. Temperature



Figure 10. Rise and Fall Time vs. Temperature



Figure 11. Enable Propagation Delay vs. Temperature



Figure 12. Switching Time vs. Temperature

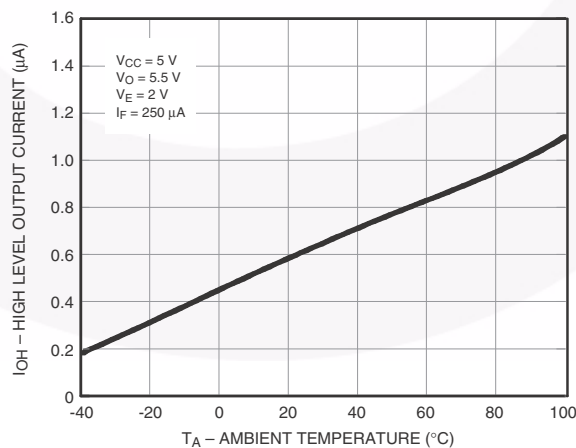


Figure 13. High Level Output Current vs. Temperature

Typical Performance Curves (Continued)

For Dual-Channel Devices: HCPL2630M and HCPL2631M



Figure 14. Low Level Output Voltage vs. Ambient Temperature



Figure 15. Input Diode Forward Voltage vs. Forward Current



Figure 16. Switching Time vs. Forward Current



Figure 17. Low Level Output Current vs. Ambient Temperature

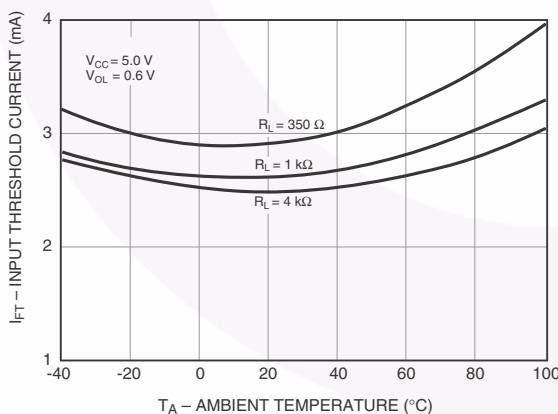


Figure 18. Input Threshold Current vs. Ambient Temperature



Figure 19. Output Voltage vs. Input Forward Current

Typical Performance Curves (Continued)

For Dual-Channel Devices: HCPL2630M and HCPL2631M



Figure 20. Pulse Width Distortion vs. Temperature

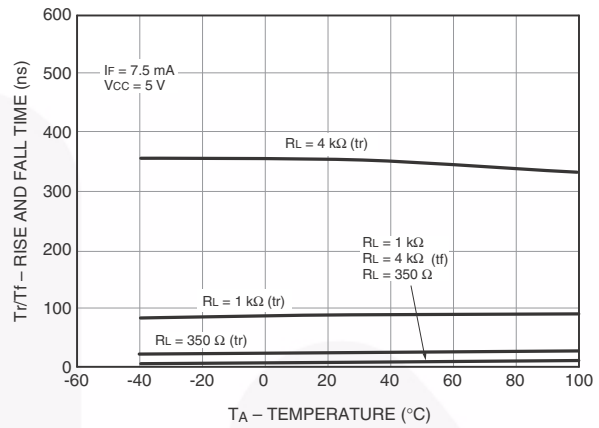


Figure 21. Rise and Fall Time vs. Temperature



Figure 22. Switching Time vs. Temperature



Figure 23. High Level Output Current vs. Temperature

Test Circuits



Figure 24. Test Circuit and Waveforms for t_{PLH} , t_{PHL} , t_r and t_f



Figure 25. Test Circuit t_{EHL} and t_{ELH}

Test Circuits (Continued)



Figure 26. Test Circuit Common Mode Transient Immunity

Reflow Profile



| Profile Feature | Pb-Free Assembly Profile |
|---------------------------------|--------------------------|
| Temperature Min. (Tsmín) | 150°C |
| Temperature Max. (Tsmáx) | 200°C |
| Time (ts) from (Tsmín to Tsmáx) | 60 to 120 s |
| Ramp-up Rate (tL to tp) | 3°C/second maximum |
| Liquidous Temperature (TL) | 217°C |
| Time (tL) Maintained Above (TL) | 60 to 150 s |
| Peak Body Package Temperature | 260°C +0°C / -5°C |
| Time (tp) within 5°C of 260°C | 30 s |
| Ramp-down Rate (TP to TL) | 6°C/s maximum |
| Time 25°C to Peak Temperature | 8 minutes maximum |

Figure 27. Reflow Profile

Ordering Information

| Part Number | Package | Packing Method |
|-------------|---|--------------------------------------|
| 6N137M | DIP 8-Pin | Tube (50 units per tube) |
| 6N137SM | SMT 8-Pin (Lead Bend) | Tube (50 units per tube) |
| 6N137SDM | SMT 8-Pin (Lead Bend) | Tape and Reel (1,000 units per reel) |
| 6N137VM | DIP 8-Pin, DIN EN/IEC 60747-5-5 Option | Tube (50 units per tube) |
| 6N137SVM | SMT 8-Pin (Lead Bend), DIN EN/IEC 60747-5-5 Option | Tube (50 units per tube) |
| 6N137SDVM | SMT 8-Pin (Lead Bend), DIN EN/IEC 60747-5-5 Option | Tape and Reel (1,000 units per reel) |
| 6N137TVM | DIP 8-Pin, 0.4" Lead Spacing, DIN EN/IEC 60747-5-5 Option | Tube (50 units per tube) |
| 6N137TSVM | SMT 8-Pin, 0.4" Lead Spacing, DIN EN/IEC 60747-5-5 Option | Tube (50 units per tube) |
| 6N137TSR2VM | SMT 8-Pin, 0.4" Lead Spacing, DIN EN/IEC 60747-5-5 Option | Tape and Reel (1,000 units per reel) |

Note:

The product orderable part number system listed in this table also applies to the HCPL2601M, HCPL2611M, HCPL2630M and HCPL2631M product families.

Marking Information

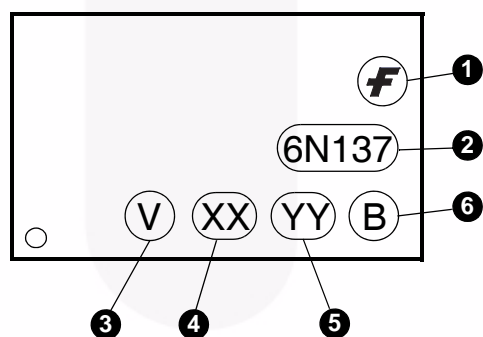


Figure 28. Top Mark

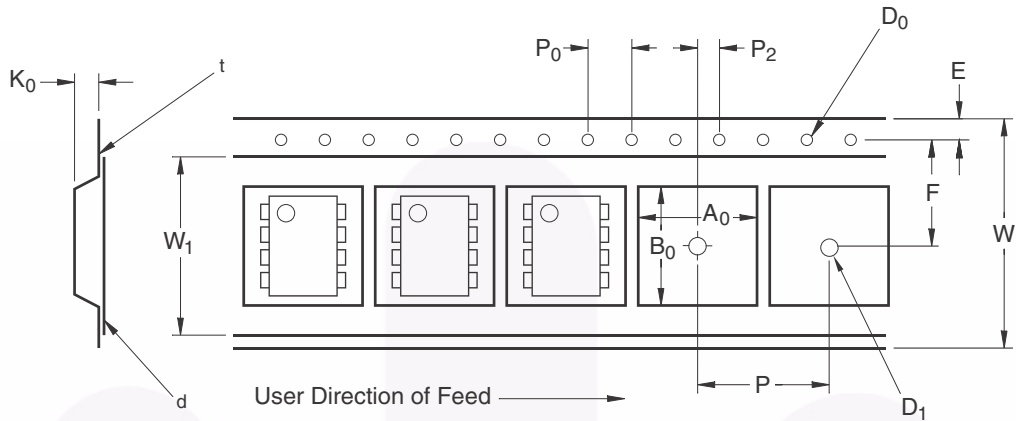
| Definitions | |
|-------------|---|
| 1 | Fairchild Logo |
| 2 | Device Number |
| 3 | DIN EN/IEC60747-5-5 Option (only appears on component ordered with this option) |
| 4 | Two Digit Year Code, e.g., '16' |
| 5 | Two Digit Work Week Ranging from '01' to '53' |
| 6 | Assembly Package Code |

Carrier Tape Specifications (Option SD)



| Symbol | Description | Dimension in mm |
|----------------|------------------------------------|-----------------|
| W | Tape Width | 16.0 ± 0.3 |
| t | Tape Thickness | 0.30 ± 0.05 |
| P ₀ | Sprocket Hole Pitch | 4.0 ± 0.1 |
| D ₀ | Sprocket Hole Diameter | 1.55 ± 0.05 |
| E | Sprocket Hole Location | 1.75 ± 0.10 |
| F | Pocket Location | 7.5 ± 0.1 |
| P ₂ | | 2.0 ± 0.1 |
| P | Pocket Pitch | 12.0 ± 0.1 |
| A ₀ | Pocket Dimensions | 10.30 ± 0.20 |
| B ₀ | | 10.30 ± 0.20 |
| K ₀ | | 4.90 ± 0.20 |
| W ₁ | Cover Tape Width | 13.2 ± 0.2 |
| d | Cover Tape Thickness | 0.1 Maximum |
| | Maximum Component Rotation or Tilt | 10° |
| R | Minimum Bending Radius | 30 |

Carrier Tape Specifications (Option TSR2)



| Symbol | Description | Dimension in mm |
|----------------|------------------------------------|-----------------|
| W | Tape Width | 24.0 ± 0.3 |
| t | Tape Thickness | 0.40 ± 0.1 |
| P ₀ | Sprocket Hole Pitch | 4.0 ± 0.1 |
| D ₀ | Sprocket Hole Diameter | 1.55 ± 0.05 |
| E | Sprocket Hole Location | 1.75 ± 0.10 |
| F | Pocket Location | 11.5 ± 0.1 |
| P ₂ | | 2.0 ± 0.1 |
| P | Pocket Pitch | 16.0 ± 0.1 |
| A ₀ | Pocket Dimensions | 12.80 ± 0.1 |
| B ₀ | | 10.35 ± 0.1 |
| K ₀ | | 5.7 ± 0.1 |
| W ₁ | Cover Tape Width | 21.0 ± 0.1 |
| d | Cover Tape Thickness | 0.1 Maximum |
| | Maximum Component Rotation or Tilt | 10° |
| R | Minimum Bending Radius | 30 |



LAND PATTERN RECOMMENDATION



NOTES:

- A) NO STANDARD APPLIES TO THIS PACKAGE
- B) ALL DIMENSIONS ARE IN MILLIMETERS.
- C) DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSION
- D) DWG FILENAME AND REVISION: MKT-N08Lrev2.





- NOTES:
 A) NO STANDARD APPLIES TO THIS PACKAGE
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 D) DRAWING FILENAME AND REVISION: MKT-N08GREV7





LAND PATTERN RECOMMENDATION



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PIN 1

15.0° (MAX)

10.16 (TYP)

0.20-0.40



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